

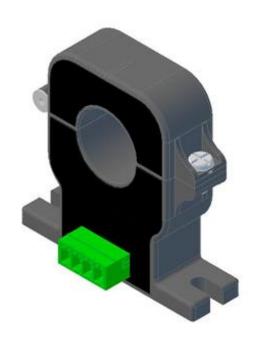
## Hall Effect Current Sensor HFB010...050T01

 $I_{PN} = 10A...50A$ 









#### **Features**

- . Split core type
- . Voltage output
- . Panel mounting type

#### Advantage

- . Excellent accuracy
- . Very good linearity
- . Low temperature drift
- . Optimized response time
- . No insertion losses
- . High immunity to external interference
- . Current overload capability.

### **Applications**

- . Used for measurement of electric current DC
- . Pulsed in electric & electronic equipment

### **Application domain**

- Commercial
- . Industrial

#### **Maximum ratings**

Parameter	Symbol	Value	Unit
Maximum supply voltage (working) +20 to+60°C	<u>+</u> Uc	+5.0	V
Primary conductor temperature	Ts	85	°C
maximum steady state primary current) +20 to +60°C	I <sub>PN</sub>	10 to 50A	A
RMS Voltage For Ac Insulation Test,50hz,1 Min	U <sub>d</sub>	3.0	KV
Comparative Tracking Index (CTI)		275	
Insulation Resistance	R <sub>is</sub>	>1000	MΩ



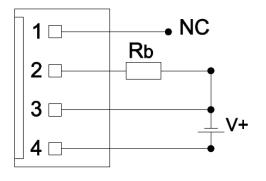
Product Range HFB010...050T01

Product Code	Primary Nominal Current			
HFB010T01	10A			
HFB025T01	25A			
HFB050T01	50A			

#### **Electrical data**

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Burden Resistance	R <sub>b</sub>			10000(min.)		Ω
Output Voltage @I <sub>PN</sub> (V <sub>out</sub> )	Vout	@±I <sub>PN</sub> , R <sub>b</sub> = 10KΩ,		1.225 ± 3.0		V
Supply Voltage (± 5%)	<u>+</u> Uc			+5.0		V
Current Consumption at @ +5v(Ic)	lout			13 Typical		mA
Overall Accuracy At I <sub>PN</sub>	X <sub>G</sub>	@25°C		<1		%
Linearity Error	$\Sigma_{L}$	-40 to 85 °C		<1.0		%
Output offset Voltage @ $I_P = 0$ ( $V_{off}$ )	V <sub>off</sub>			1.225 ± 0.062		mV
Hysteresis offset Voltage	V <sub>он</sub>	@I <sub>P</sub> = 0 after a primary current of I <sub>PN</sub>		±1		mV
Temperature coefficient of V <sub>out</sub>	TV <sub>OE</sub>	-40 to +85 °C		TBD		% of rdg/K
Reaction Time @ 90% Of I <sub>PN</sub>	t <sub>ra</sub>			TBD		μs
Frequency Bandwidth @ -3db (fbw)	BW	-3dB, small signal bw		DC		KHz
di/dt accurately followed	di/dt			>50		A/ μs
Ambient Operating Temperature	T <sub>A</sub>			+20 to +60		°C
Ambient Storage Temperature	Ts			-40 to +85		°C
Mass	m			70		g

# **Connection Diagram**



## Input & Output Characteristics



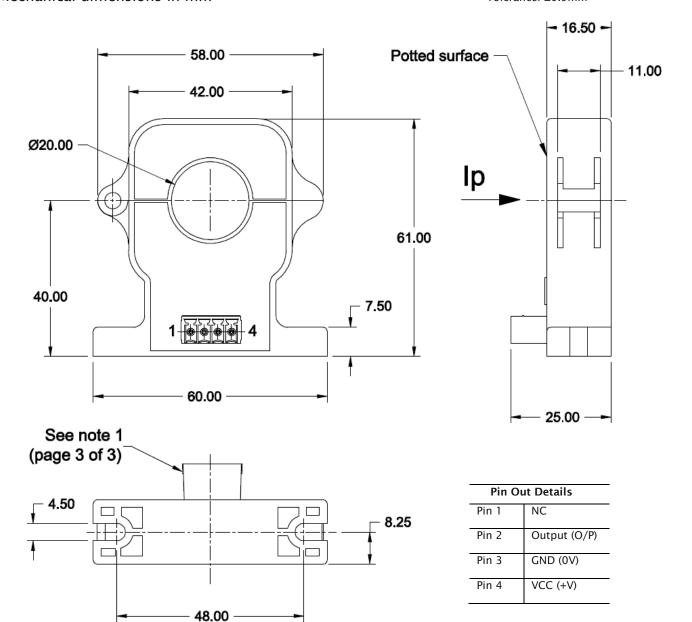


#### Mechanical dimensions in mm

Date:15.12.2017

Rev: 01(Provisional)

Tolerance: ±0.5mm





### **Safety**

Date:15.12.2017

Rev: 01(Provisional)

- This Current Transformer must be used in electric/electronic equipment with respect to applicable standards and safety requirements in accordance with the manufacturer's operating instructions.
- Caution, risk of electrical shock

When operating the Current Transformer, certain parts of the module can carry hazardous voltage (eg. primary busbar, power supply).

- Ignoring this warning can lead to injury and/or cause serious damage.
- A protective housing or additional shield could be used.
- Main supply must be to be disconnected.
- If IP flows in the direction of the Arrow Isek is positive
- Over currents (»I<sub>PN</sub>) or the missing of the supply voltage can cause an additional remaining magnetic offset
- The temperature of the primary conductor may not exceed 100 °C
- This Sensors may only be used in electrical or electronic systems which fulfil the relevant regulations (Standards, EMC Requirements...)
- Pay attention to protect non-isolated high-voltage current carrying parts against direct contact (e.g. with a protective housing)
- When installing this sensor, you must ensure that the safe separation (between primary circuit and secondary circuit) is maintained over the whole circuits and their connections
- Disconnecting the main power must be possible